Bridge Rectifiers, 0.5 A

MB10S

Description

The MB family of bridge rectifiers is a 0.5 A rectifier family that achieves high surge current absorption within a very small foot print. Within its small 35 mm² form factor, the MB family shines in its surge capability. In order to absorb high surge currents, the design supports a 35 A I_{FSM} rating and a 5.0 A²Sec I^2T rating. Devices in the family are also rated to breakdown voltages of up to 1000 V. These features make the MB family ideal for small power supplies that need a little extra surge capability.

Features

- Low-Leakage
- Surge Overload Rating: 35 A peak
- Ideal for Printed Circuit Board
- UL Certified: UL #E258596
- This Device is Pb-Free and RoHS Compliant



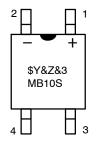
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SOIC4 W CASE 751EP

MARKING DIAGRAM



\$Y = ON Semiconductor Logo &Z = Assembly Plant Code

&3 = 3-Digit Data Code (Year & Week)

MB10S = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

MB10S

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|--------------------|---|-------------|------|
| V_{RRM} | Maximum Repetitive Reverse Voltage | 1000 | V |
| V_{RMS} | Maximum RMS Bridge Input Voltage | 700 | V |
| V_{R} | DC Reverse Voltage (Rated V _R) | 1000 | V |
| I _{F(AV)} | Average Rectified Forward Current at T _A = 50°C On Glass-Epoxy PCB On Aluminum Substrate | 0.5 0.8 | А |
| I _{FSM} | Non-Repetitive Peak Forward Surge Current: 8.3 ms Single Half-Sine-Wave | 35 | Α |
| T _{STG} | Storage Temperature Range | -55 to +150 | °C |
| T_J | Operating Junction Temperature Range | -55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Symbol | Parameter | Value | Unit |
|----------------|---|-------|------|
| P_{D} | Power Dissipation | 1.4 | W |
| $R_{	hetaJA}$ | Thermal Resistance, Junction to Ambient, per Leg (Note 1) | 85 | °C/W |
| $R_{	heta JL}$ | Thermal Resistance, Junction to Lead, per Leg (Note 1) | 20 | °C/W |

^{1.} Device mounted on PCB with 0.5 \times 0.5 inch (13 \times 13 mm) lead length.

ELECTRICAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted)

| Symbol | Parameter | Conditions | Value | Unit |
|------------------|--|-------------------------------------|-------|------------------|
| V_{F} | Maximum Forward Voltage, per Diode | I _F = 0.5 A | 1.0 | V |
| I _R | Maximum Reverse Current, per Diode at Rated V _R | T _A = 25°C | 5.0 | μΑ |
| | | T _A = 125°C | 0.5 | mA |
| l ² t | I ² t Rating for Fusing | t < 8.3 ms | 5.0 | A ² s |
| C _T | Typical Capacitance, per Diode | V _R = 4.0 V, f = 1.0 MHz | 13 | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

| Part Number | Marking | Package | Shipping [†] |
|-------------|---------|----------------------|-----------------------|
| MB10S | MB10S | SOIC4 W (Pb-Free) | 3,000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MB10S

TYPICAL PERFORMANCE CHARACTERISTICS

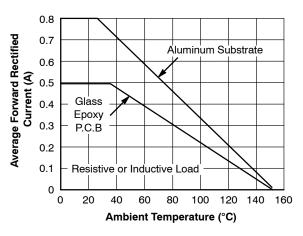


Figure 1. Derating Curve for Output Rectified Current

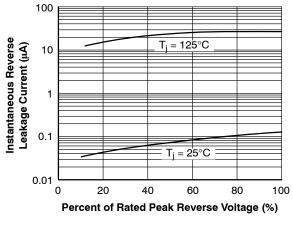


Figure 2. Typical Reverse Leakage Characteristics
Per Leg

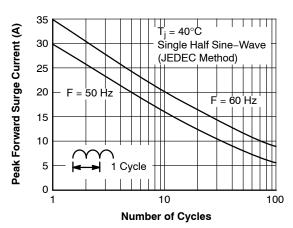


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current Per Leg

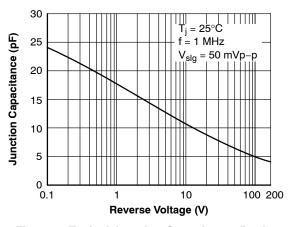


Figure 4. Typical Junction Capacitance Per Leg

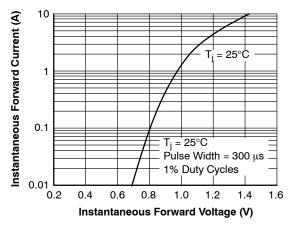
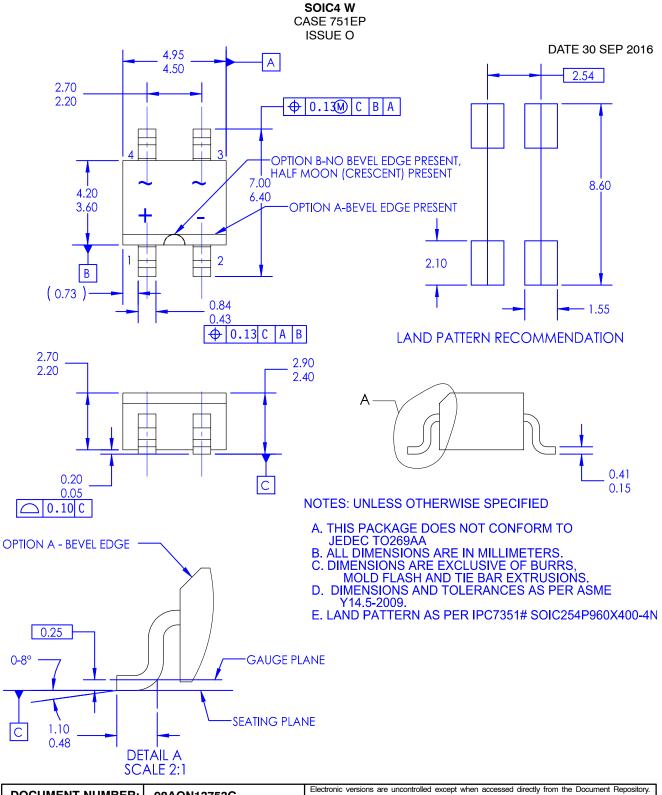


Figure 5. Typical Forward Voltage Characteristics
Per Leg



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|------------------|-------------|---|-------------|
| DESCRIPTION: | SOIC4 W | | PAGE 1 OF 1 |

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